TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC5087

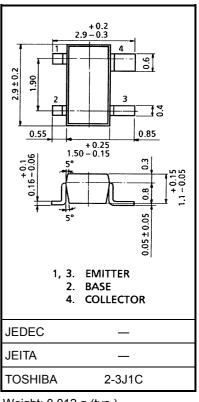
VHF~UHF Band Low Noise Amplifier Applications

Unit: mm

- Low noise figure, high gain.
- NF = 1.1dB, $|S_{21e}|^2 = 13dB$ (f = 1 GHz)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V_{CBO}	20	V	
Collector-emitter voltage	V _{CEO}	12	V	
Emitter-base voltage	V _{EBO}	3	V	
Base current	Ι _Β	40	mA	
Collector current	I _C	80	mA	
Collector power dissipation	P _C	150	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T _{stg}	−55~125	°C	



Weight: 0.012 g (typ.)

Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Transition frequency	f _T	V _{CE} = 10 V, I _C = 20 mA	5	7	_	GHz	
Insertion gain	S _{21e} ² (1)	V _{CE} = 10 V, I _C = 20 mA, f = 500 MHz	_	18	_	dB	
insertion gain	S _{21e} ² (2)	V _{CE} = 10 V, I _C = 20 mA, f = 1 GHz	13	_	ub.		
Noise figure	NF (1)	$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}, f = 500 \text{ MHz}$	_	1	_	dB	
Noise ligure	NF (2)	$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}, f = 2 \text{ GHz}$		1.1	2	T GB	

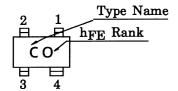
Electrical Characteristics (Ta = 25°C)

Characteristics Symbol		Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 10 \text{ V}, I_{E} = 0$	_	_	1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 1 V, I _C = 0	_	_	1	μΑ
DC current gain	h _{FE} (Note 1)	V _{CE} = 10 V, I _C = 20 mA	80	_	240	
Output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz (Note 2)	_	1.1	1.6	pF
Reverse transfer capacitance	C _{re}	$\frac{1}{2}$ VCB = 10 V, $\frac{1}{12}$ = 0, $\frac{1}{1}$ = 1 MHZ (Note 2)	_	0.65	1.05	pF

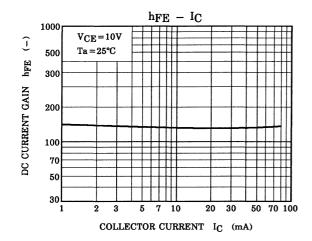
Note 1: hFE classification O: 80~160, Y: 120~240

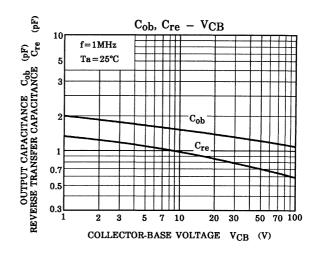
Note 2: C_{re} is measured by 3 terminal method with capacitance bridge.

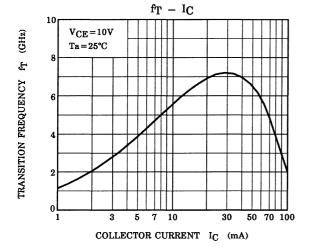
Marking

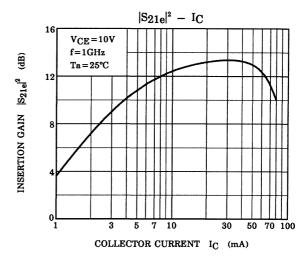


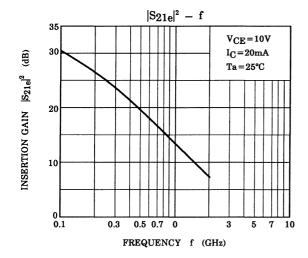
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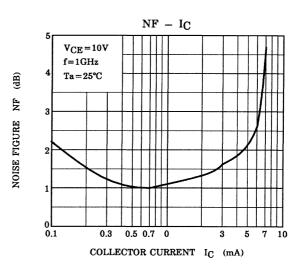


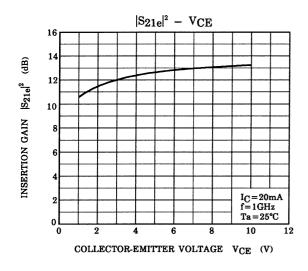


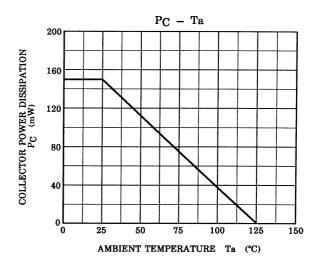












S-Parameter $Z_O = 50 \Omega$, Ta = 25°C

$V_{\text{CE}} = 10 \ \text{V}, \ I_{\text{C}} = 5 \ \text{mA}$

Frequency	S11		S21		S12		S22	
MHz	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.793	-82.4	11.923	133.4	0.050	52.7	0.788	-36.4
400	0.736	-128.0	7.835	108.5	0.066	38.0	0.584	-53.4
600	0.719	-152.1	5.578	94.5	0.071	34.1	0.490	-63.5
800	0.701	-168.6	4.279	84.4	0.073	33.9	0.445	-72.2
1000	0.698	178.9	3.451	76.6	0.074	36.7	0.424	-80.5
1200	0.697	168.3	2.855	69.9	0.076	40.8	0.413	-88.9
1400	0.699	159.4	2.440	64.0	0.078	46.6	0.404	-97.3
1600	0.703	150.8	2.121	59.3	0.084	52.5	0.401	-105.4
1800	0.713	142.9	1.876	54.5	0.091	58.3	0.398	-112.6
2000	0.722	134.7	1.681	50.3	0.100	63.5	0.398	-119.6

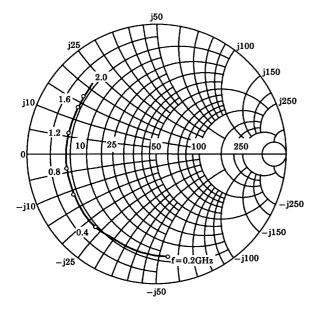
$V_{CE} = 10 \text{ V}, I_C = 20 \text{ mA}$

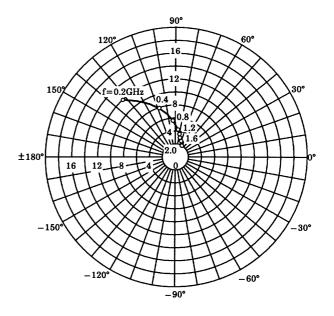
Frequency	S11		S21		S12		S22	
MHz	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.655	-129.4	20.724	113.2	0.031	48.0	0.496	-59.6
400	0.650	-161.5	11.288	95.5	0.040	50.4	0.319	-74.1
600	0.660	-176.3	7.643	86.4	0.049	56.4	0.263	-83.5
800	0.666	172.8	5.758	79.6	0.059	60.0	0.242	-92.9
1000	0.667	164.0	4.605	74.2	0.070	63.6	0.233	-102.0
1200	0.668	156.8	3.809	69.3	0.080	65.9	0.229	-111.0
1400	0.677	148.4	3.277	65.1	0.091	68.2	0.226	-119.1
1600	0.676	141.1	2.862	61.2	0.104	70.0	0.223	-126.5
1800	0.688	133.9	2.559	57.5	0.117	71.2	0.220	-132.4
2000	0.690	126.7	2.303	54.1	0.131	72.4	0.217	-137.8

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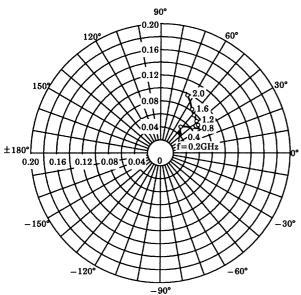
 $\begin{array}{l} S_{11e} \\ V_{CE} = 10V \\ I_{C} = 5 mA \\ Ta = 25 ^{\circ}C \\ (Unit: \Omega) \end{array}$



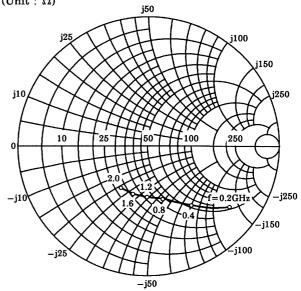






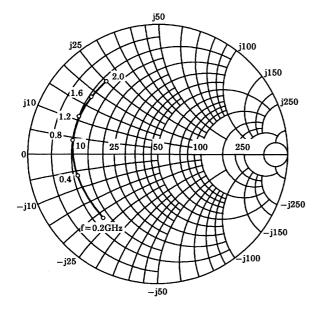


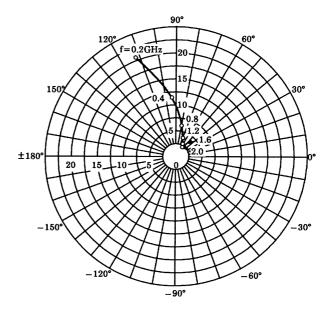




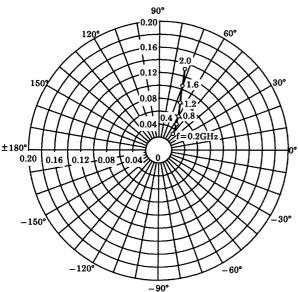
 $\begin{array}{l} S_{11e} \\ V_{CE} = 10V \\ I_{C} = 20 mA \\ Ta = 25 ^{\circ}C \\ (Unit: \Omega) \end{array}$



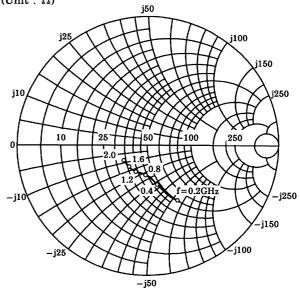




 $\begin{array}{l} S_{12e} \\ V_{CE} = 10V \\ I_{C} = 20 \text{mA} \\ Ta = 25 ^{\circ}\text{C} \end{array}$



 $\begin{array}{l} S_{22e} \\ V_{CE} = 10V \\ I_{C} = 20 mA \\ Ta = 25 ^{\circ}C \\ (Unit: \Omega) \end{array}$



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